TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS VI-H)

# **TPCA8051-H**

Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q<sub>SW</sub> = 18 nC (typ.)
- Low drain-source ON-resistance:  $R_{DS}$  (ON) = 6.0  $m\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 96 S$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \mu A (max) (V_{DS} = 80 V)$
- Enhancement mode:  $V_{th} = 1.3 \text{ to } 2.3 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1.0 \text{ mA})$

### Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	80	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	80	V	
Gate-source voltage		V <sub>GSS</sub>	±20	\\\\\	
Drain current	DC (Note 1)	ID((	28	A	
	Pulsed (Note 1)	IDP	84	^	
Drain power dissipation	on $(Tc = 25^{\circ}C)$	(PD	45	//w	
Drain power dissipation	on (t = 10 s) (Note 2a)	PD	2.8	W	
Drain power dissipation	on (t = 10 s) (Note 2b)	D <sub>D</sub>	1,6	W	
Single-pulse avalanche energy (Note 3)		EAS	255	mJ	
Avalanche current		I <sub>AR</sub>	28	Α	
Repetitive avalanche energy (Tc = 25°C) (Note 4)		EAR	2.03	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: For Notes 1 to 4, refer to the next page.

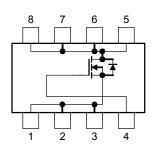
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Weight: 0.069 g (typ.)

### **Circuit Configuration**

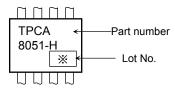


Start of commercial production 2008-10

#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

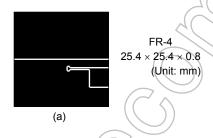
### Marking (Note 5)

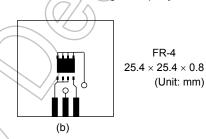


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)





Note 3:  $V_{DD} = 24 \text{ V}$ ,  $T_{Ch} = 25^{\circ}\text{C}$  (initial),  $L = 100 \mu\text{H}$ ,  $R_G = 25 \Omega$ ,  $I_{AR} = 28 \text{ A}$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)

Week of manufacture

(01 for the first week of the year, continuing up to 52 or 53)

Year of manufacture (The last digit of the year)



### Electrical Characteristics (Ta = 25°C)

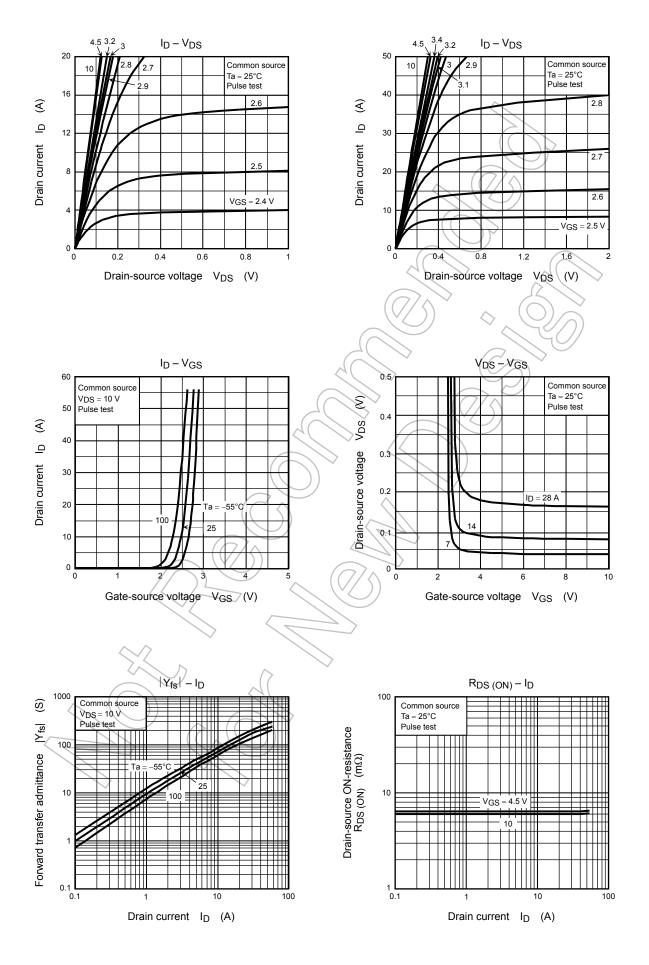
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V		_	10	μА
Drain-source breakdown voltage		V (BR) DSS	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	80	_	_	٧
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	60	_	_	
Gate threshold vo	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.3	) /_	2.3	V
Drain-source ON-resistance		Б	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 14 A	) <u> </u>	6.4	9.8	- mΩ
		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 14 A	$\mathcal{D}$	6.0	9.4	
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 14 A	48	96	_	S
Input capacitance	9	C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	5800	7540	pF
Reverse transfer	capacitance	C <sub>rss</sub>		_	150	210	
Output capacitan	ce	Coss		/	520	$\nearrow$	
Gate resistance		rg	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	-6	1.0	1.5	Ω
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 10 V I <sub>D</sub> = 14 A O V <sub>OUT</sub> C C C C C C C C C C C C C C C C C C C		3.4	) —	
	Turn-on time	t <sub>on</sub>		$\sqrt{2}$	13	_	ne
	Fall time	t <sub>f</sub>	4.7.7.4 W 9.7.7.1 S. 2.2.1 S.		6.3	_	ns -
	Turn-off time	t <sub>off</sub>	V <sub>DD</sub> ≈ 40 V Duty ≤ 1%, t <sub>w</sub> = 10 μs	_	66	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 64 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 28 \text{ A}$	_	91	_	-
			$V_{DD} \approx 64 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 28 \text{ A}$	_	47	_	
Gate-source char	rge 1	Q <sub>gs1</sub>		_	16	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>	$V_{DD} \approx 64 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 28 \text{ A}$	_	11	_	
Gate switch char	ge (7/	Q <sub>SW</sub>		_	18	_	

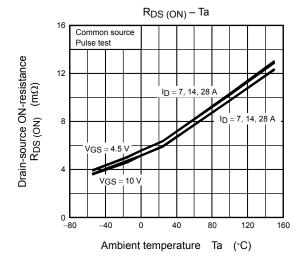
# Source-Drain Ratings and Characteristics (Ta = 25°C)

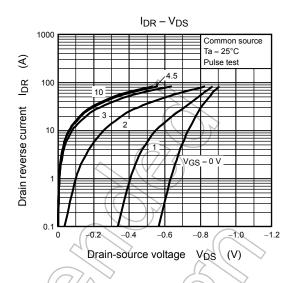
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I <sub>DRP</sub>	> -	_	_	84	Α
Forward voltage (diode)	V <sub>DSF</sub>	$I_{DR} = 28 \text{ A}, V_{GS} = 0 \text{ V}$			-1.2	V

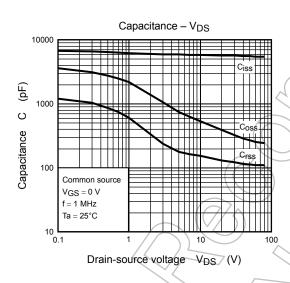
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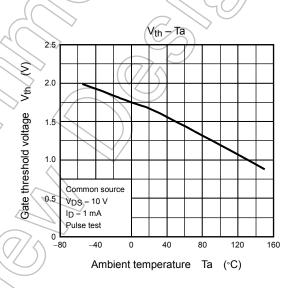
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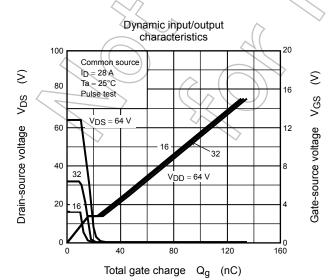






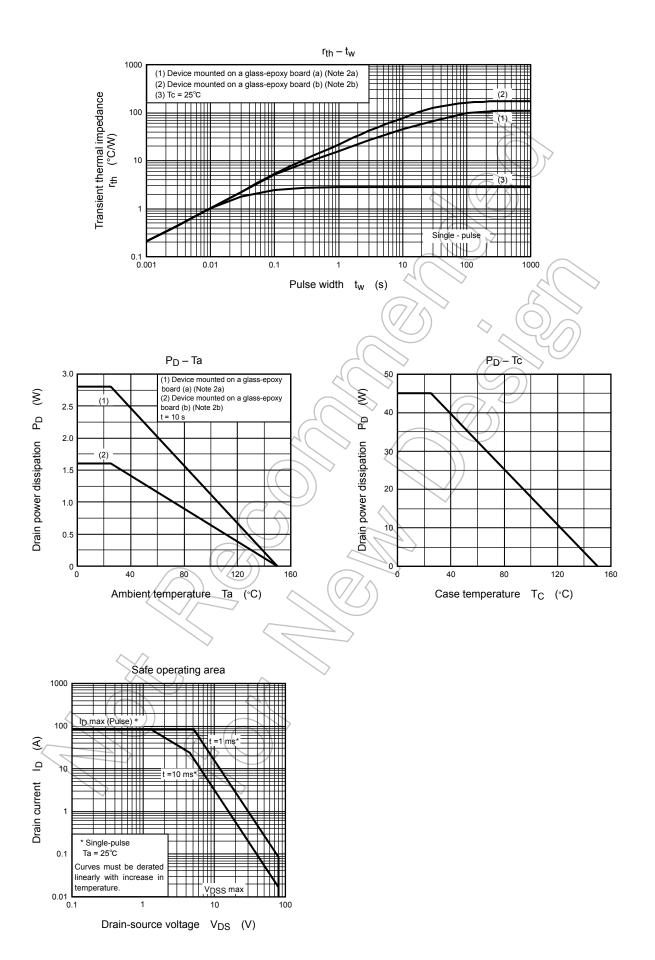






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